



BCP 51/ 52/ 53

PNP MEDIUM POWER TRANSISTORS IN SOT223

Features

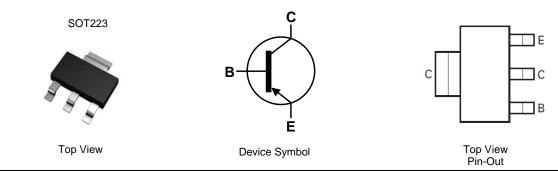
- BV_{CEO} > -45V, -60V & -80V
- I_C = -1A High Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < -500mV @ -0.5A
- Gain Groups 10 and 16
- Complementary NPN Types: BCP54, 55 and 56
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (Approximate)

Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel	
BCP51TA	AEC-Q101	BCP 51	7	12	1,000	
BCP5110TA	AEC-Q101	BCP 5110	7	12	1,000	
BCP5116TA	AEC-Q101	BCP 5116	7	12	1,000	
BCP5116TC	AEC-Q101	BCP 5116	13	12	4,000	
BCP52TA	AEC-Q101	BCP 52	7	12	1,000	
BCP5210TA	AEC-Q101	BCP 5210	7	12	1,000	
BCP5216TA	AEC-Q101	BCP 5216	7	12	1,000	
BCP53TA	AEC-Q101	BCP 53	7	12	1,000	
BCP53QTA	Automotive	BCP 53	7	12	1,000	
BCP5310TA	AEC-Q101	BCP 5310	7	12	1,000	
BCP5316TA	AEC-Q101	BCP 5316	7	12	1,000	
BCP5316QTA	Automotive	Refer to http://diodes.	Refer to http://diodes.com/datasheets/BCP5316Q.pdf			
BCP5316TC	AEC-Q101	BCP 5316	13	12	4,000	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

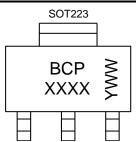
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



BCP = Product Type Marking Code, Line 1 XXXX = Product Type Marking Code, Line 2 as follows:

BCP51 = 51	BCP52 = 52
BCP5110 = 5110	BCP5210 = 521
BCP5116 = 5116	BCP5216 = 521

6 YWW = Date Code Marking

BCP5316 = 5316

0

BCP53 = 53

BCP5310 = 5310

Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W =$ Week Code (01~53)

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Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCP51	BCP52	BCP53	Unit
Collector-Base Voltage	V _{CBO}	-45	-60	-100	V
Collector-Emitter Voltage	V _{CEO}	-45	-60	-80	V
Emitter-Base Voltage	V _{EBO}		-5		
Continuous Collector Current	lc	-1			A
Peak Pulse Collector Current	I _{CM}	-2			
Continuous Base Current	IB	-100			~ ^
Peak Pulse Base Current	I _{BM}	-200			mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	PD	2	W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	62	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R _{θJL}	19.4	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-65 to +150	°C	

ESD Ratings (Note 8)

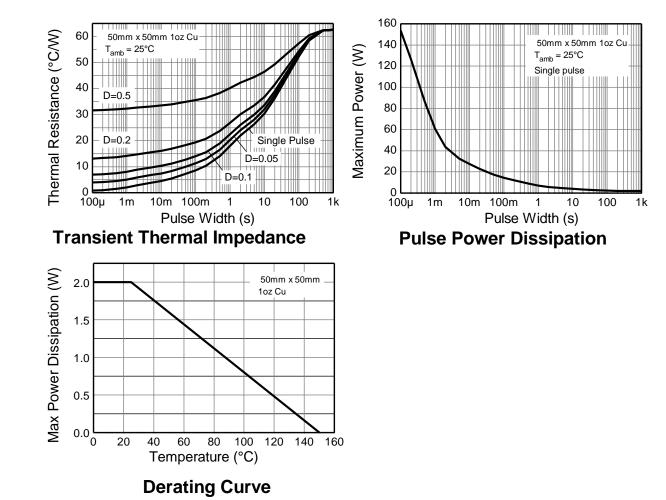
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

6. For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in steady-state.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information

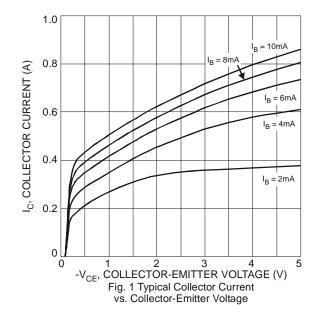


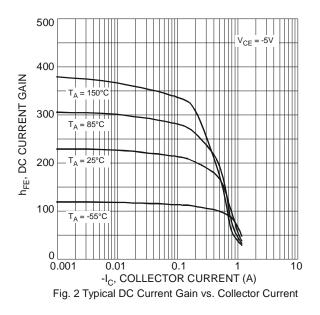


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

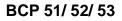
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BCP51 BCP52 BCP53	BV _{CBO}	-45 -60 -100	_	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BCP51 BCP52 BCP53	BV _{CEO}	-45 -60 -80	_	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage		BV _{EBO}	-5		_	V	I _E = -10μΑ
Collector Cut-Off Current		I _{CBO}	_	_	-0.1 -20	μA	V _{CB} = -30V V _{CB} = -30V, T _A = +150°C
Emitter Cut-Off Current		I _{EBO}	—	—	-20	nA	$V_{EB} = -4V$
Static Forward Current Transfer Ratio (Note 9)	All Versions	h _{FE}	25 40 25		 250 	_	$I_{C} = -5mA$, $V_{CE} = -2V$ $I_{C} = -150mA$, $V_{CE} = -2V$ $I_{C} = -500mA$, $V_{CE} = -2V$
	10 gain grp		63	—	160		$I_{\rm C} = -150 {\rm mA}, V_{\rm CE} = -2 {\rm V}$
	16 gain grp		100		250		$I_{C} = -150 \text{mA}, V_{CE} = -2 \text{V}$
Collector-Emitter Saturation Voltage (Note 9)		V _{CE(sat)}			-0.5	V	I _C = -500mA, I _B = -50mA
Base-Emitter Turn-On Voltage (Note 9)		V _{BE(on)}			-1.0	V	$I_{C} = -500 \text{mA}, V_{CE} = -2 \text{V}$
Transition Frequency		f⊤	150	—	—	MHz	$I_{C} = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 100MHz
Output Capacitance		Cobo			25	pF	V _{CB} = -10V, f = 1MHz

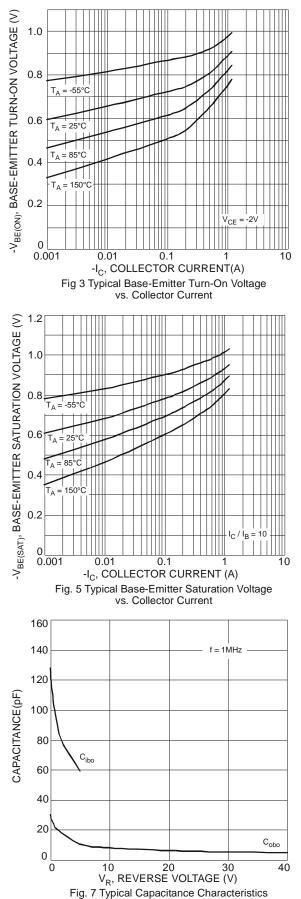
Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

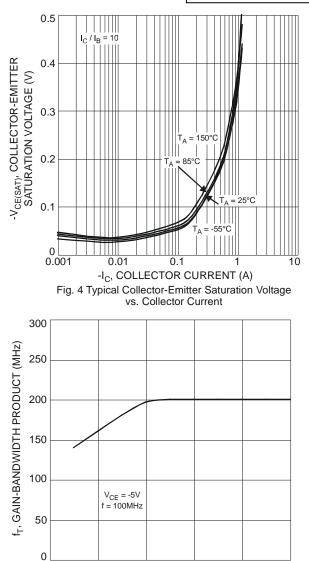














60

80

100

40

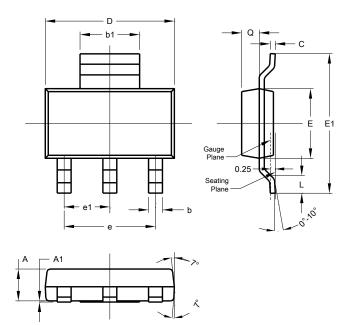
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Package Outline Dimensions

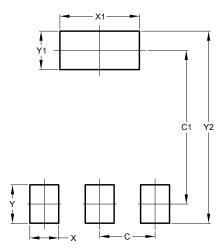
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)	
С	2.30	
C1	6.40	
Х	1.20	
X1	3.30	
Y	1.60	
Y1	1.60	
Y2	8.00	



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